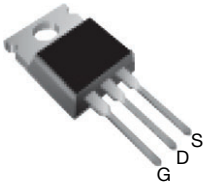
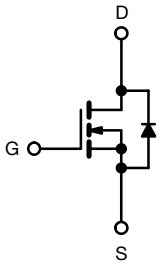
Power MOSFET

TO-220AB





N-Channel MOSFET

FEATURES

- Dynamic dV/dt rating
- Logic-level gate drive
- $R_{DS(on)}$ specified at V_{GS} = 4 V and 5 V
- 175 °C operating temperature
- Fast switching
- Ease of paralleling
- Simple drive requirements
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Available

RoHS* Available

Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

PRODUCT SUMMARY		
V_{DS} (V)	60	
$R_{DS(on)}$ (Ω)	V_{GS} = 5.0 V	0.028
Q_g (Max.) (nC)	66	
Q_{gs} (nC)	12	
Q_{gd} (nC)	43	
Configuration	Single	

DESCRIPTION

Third generation power MOSFETs from Vishay provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.

The TO-220AB package is universally preferred for all commercial-industrial applications at power dissipation levels to approximately 50 W. The low thermal resistance and low package cost of the TO-220AB contribute to its wide acceptance throughout the industry.

ORDERING INFORMATION	
Package	TO-220AB
Lead (Pb)-free	IRLZ44PbF
Lead (Pb)-free and halogen-free	IRLZ44PbF-BE3

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER			SYMBOL	LIMIT	UNIT
Drain-source voltage			V_{DS}	60	V
Gate-source voltage			V_{GS}	± 10	
Continuous drain current	V_{GS} at 5 V	T_C = 25 °C	I_D	50	A
		T_C = 100 °C		36	
Pulsed drain current [a]			I_{DM}	200	
Linear derating factor				1.0	W/°C
Single pulse avalanche energy [b]			E_{AS}	400	mJ
Maximum power dissipation	T_C = 25 °C		P_D	150	W
Peak diode recovery dV/dt [c]			dV/dt	4.5	V/ns
Operating junction and storage temperature range			T_J, T_{stg}	-55 to +175	°C
Soldering recommendations (peak temperature) [d]	For 10 s			300	
Mounting torque	6-32 or M3 screw			10	lbf · in
				1.1	N · m

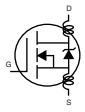
Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11)
b. V_{DD} = 25 V, starting T_J = 25 °C, L = 179 µH, R_g = 25 Ω, I_{AS} = 51 A (see fig. 12)
c. I_{SD} ≤ 51 A, dV/dt ≤ 250 A/s, V_{DD} ≤ V_{DS}, T_J ≤ 175 °C
d. 1.6 mm from case
e. Current limited by the package, (die current = 51 A)

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THERMAL RESISTANCE RATINGS				
PARAMETER	**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Maximum junction-to-ambient	R_{thJA}	-	62	°C/W
Case-to-sink, flat, greased surface	R_{thCS}	0.50	-	
Maximum junction-to-case (drain)	R_{thJC}	-	1.0	

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA		60	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	Reference to 25 °C, I_D = 1 mA		-	0.070	-	V/°C
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA		1.0	-	2.0	V
Gate-source leakage	I_{GSS}	V_{GS} = 10 V		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 60 V, V_{GS} = 0 V		-	-	25	µA
		V_{DS} = 48 V, V_{GS} = 0 V, T_J = 150 °C		-	-	250	
Drain-source on-state resistance	$R_{DS(on)}$	V_{GS} = 5.0 V	I_D = 31 A [b]	-	-	0.028	Ω
		V_{GS} = 4.0 V	I_D = 25 A [b]	-	-	0.039	
Forward transconductance	g_{fs}	V_{DS} = 25 V, I_D = 31 A [b]		23	-	-	S
Dynamic							
Input capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1.0 MHz, see fig. 5		-	3300	-	pF
Output capacitance	C_{oss}			-	1200	-	
Reverse transfer capacitance	C_{rss}			-	200	-	
Total gate charge	Q_g	V_{GS} = 5.0 V	I_D = 51 A, V_{DS} = 48 V, see fig. 6 and 13 [b]	-	-	66	nC
Gate-source charge	Q_{gs}			-	-	12	
Gate-drain charge	Q_{gd}			-	-	43	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 30 V, I_D = 51 A, R_g = 4.6 Ω, R_D = 0.56 Ω, see fig. 10 [b]		-	17	-	ns
Rise time	t_r			-	230	-	
Turn-off delay time	$t_{d(off)}$			-	42	-	
Fall time	t_f			-	110	-	
Internal drain inductance	L_D	Between lead, 6 mm (0.25") from package and center of die contact 		-	4.5	-	nH
Internal source inductance	L_S			-	7.5	-	
Drain-Source Body Diode Characteristics							
Continuous source-drain diode current	I_S	MOSFET symbol showing the integral reverse p - n junction diode 		-	-	50[c]	A
Pulsed diode forward current [a]	I_{SM}			-	-	200	
Body diode voltage	V_{SD}	T_J = 25 °C, I_S = 51 A, V_{GS} = 0 V [b]		-	-	2.5	V
Body diode reverse recovery time	t_{rr}	T_J = 25 °C, I_F = 51 A, dI/dt = 100 A/µs [b]		-	130	180	ns
Body diode reverse recovery charge	Q_{rr}			-	0.84	1.3	µC
Forward turn-on time	t_{on}	Intrinsic turn-on time is negligible (turn-on is dominated by L_S and L_D)					

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11)
b. Pulse width ≤ 300 µs; duty cycle ≤ 2 %
c. Current limited by the package, (die current = 51 A)

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

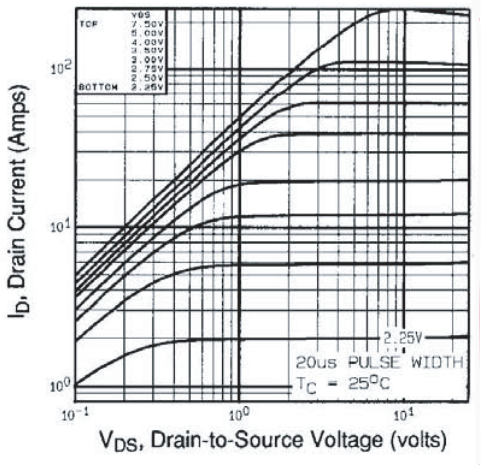


Fig. 1 - Typical Output Characteristics, T_C = 25 °C

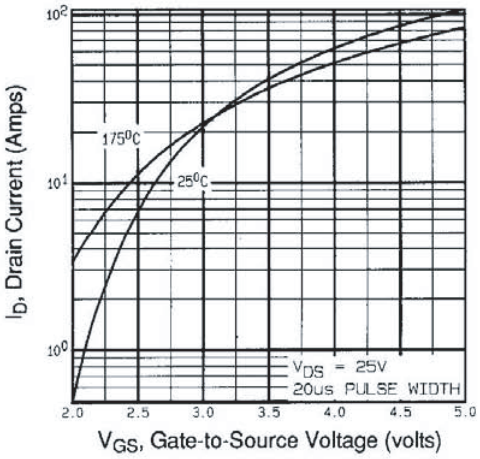


Fig. 3 - Typical Transfer Characteristics

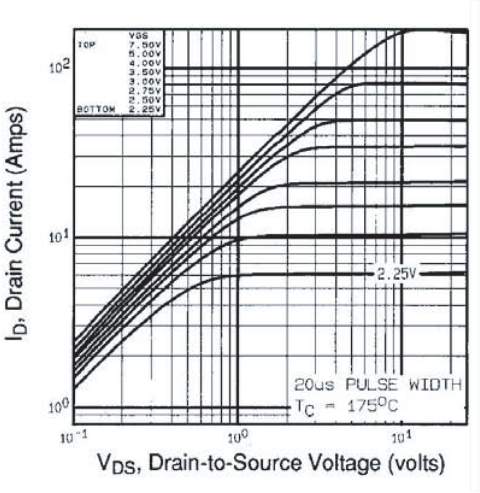


Fig. 2 - Typical Output Characteristics, T_C = 175 °C

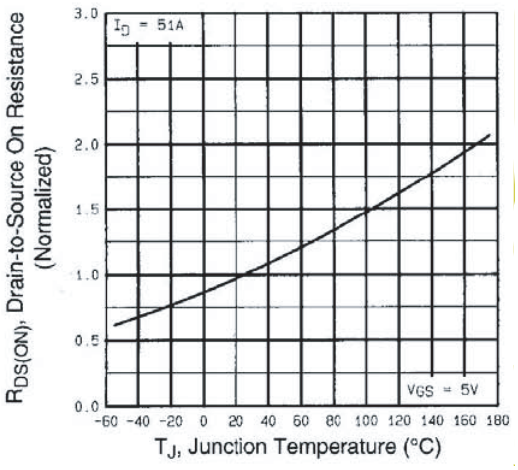


Fig. 4 - Normalized On-Resistance vs. Temperature

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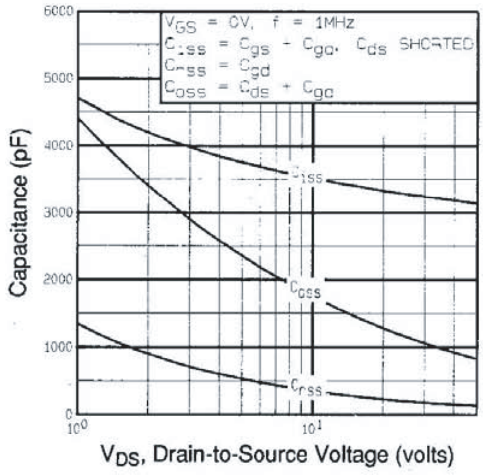


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

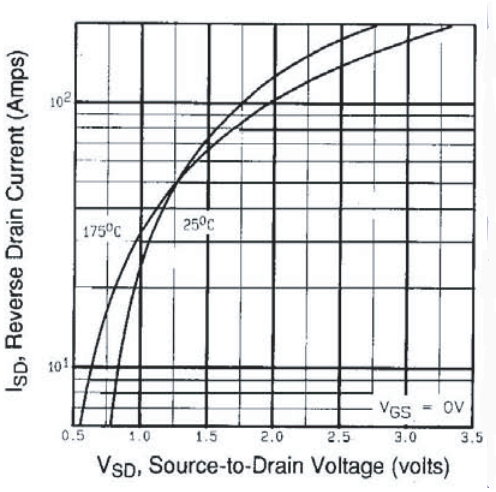


Fig. 7 - Typical Source-Drain Diode Forward Voltage

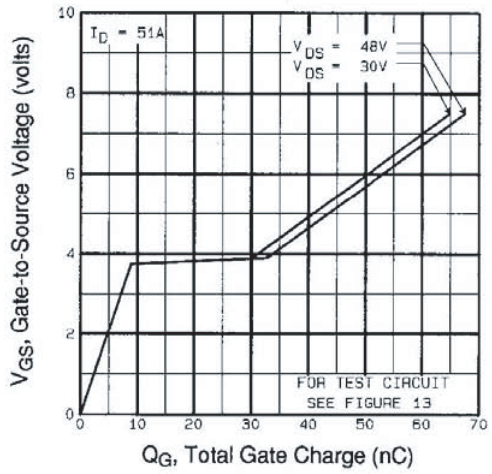


Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage

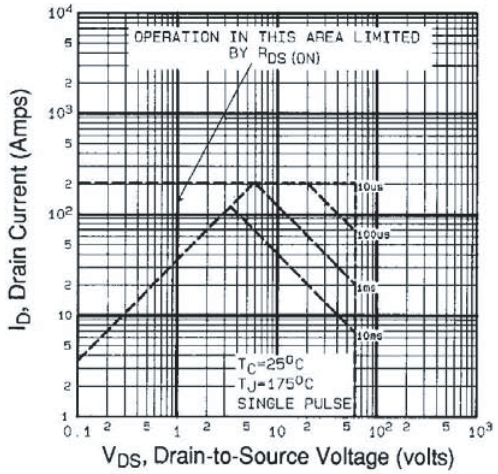


Fig. 8 - Maximum Safe Operating Area

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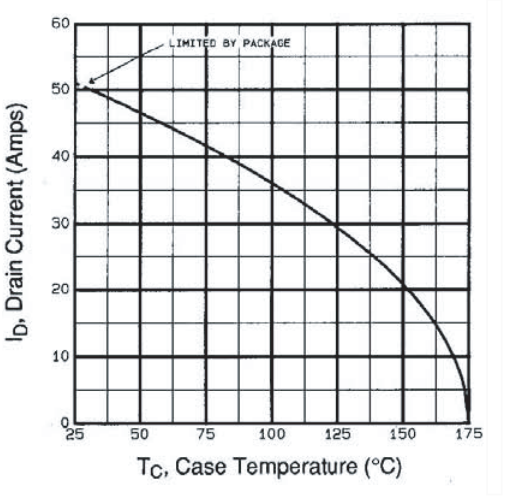


Fig. 9 - Maximum Drain Current vs. Case Temperature

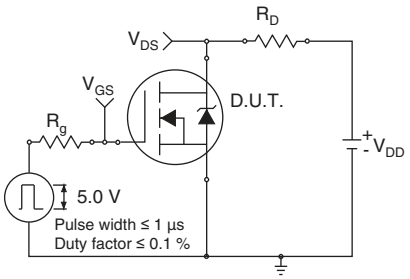


Fig. 10a - Switching Time Test Circuit

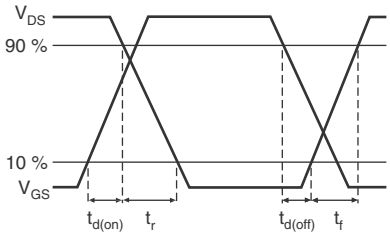


Fig. 10b - Switching Time Waveforms

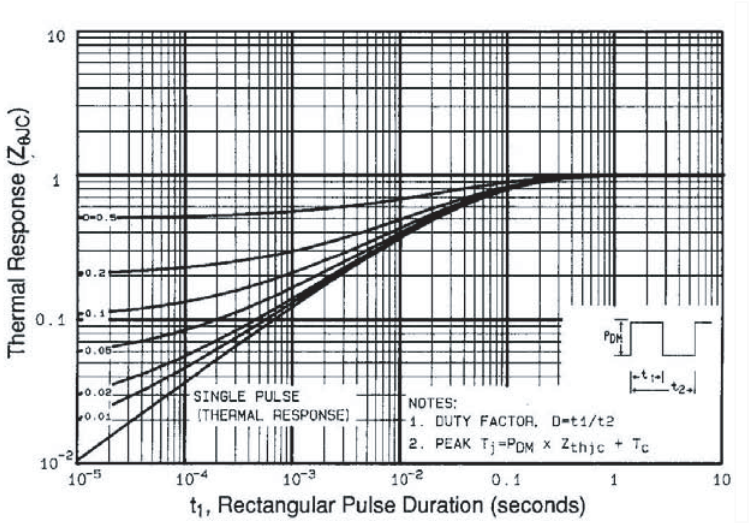


Fig. 10 - Maximum Effective Transient Thermal Impedance, Junction-to-Case

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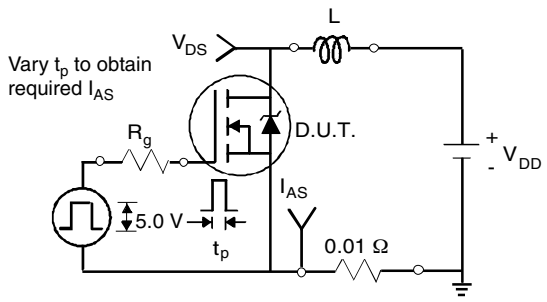


Fig. 12a - Unclamped Inductive Test Circuit

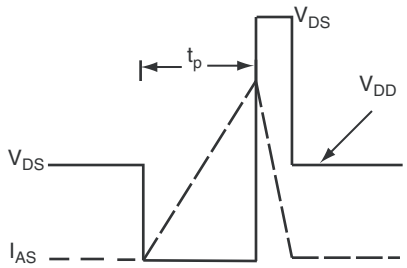


Fig. 12b - Unclamped Inductive Waveforms

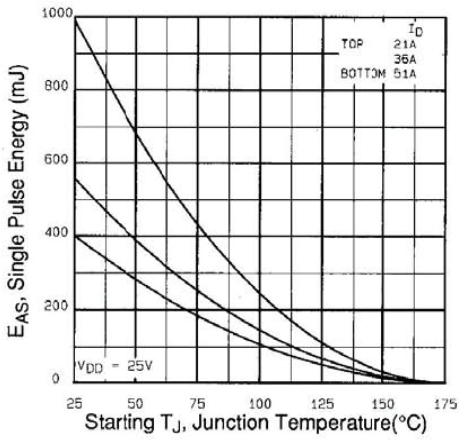


Fig. 12c - Maximum Avalanche Energy vs. Drain Current

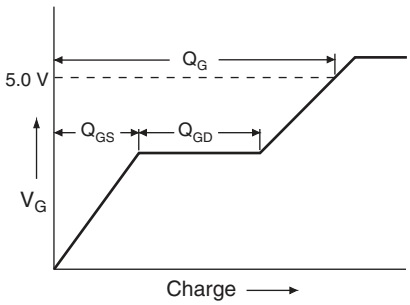


Fig. 13a - Basic Gate Charge Waveform

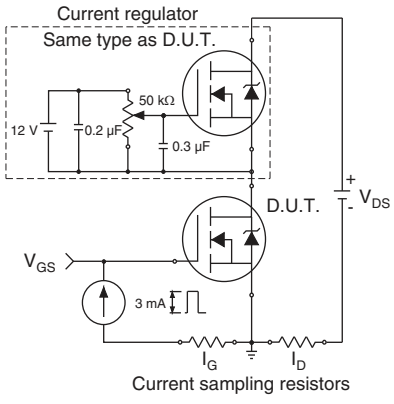
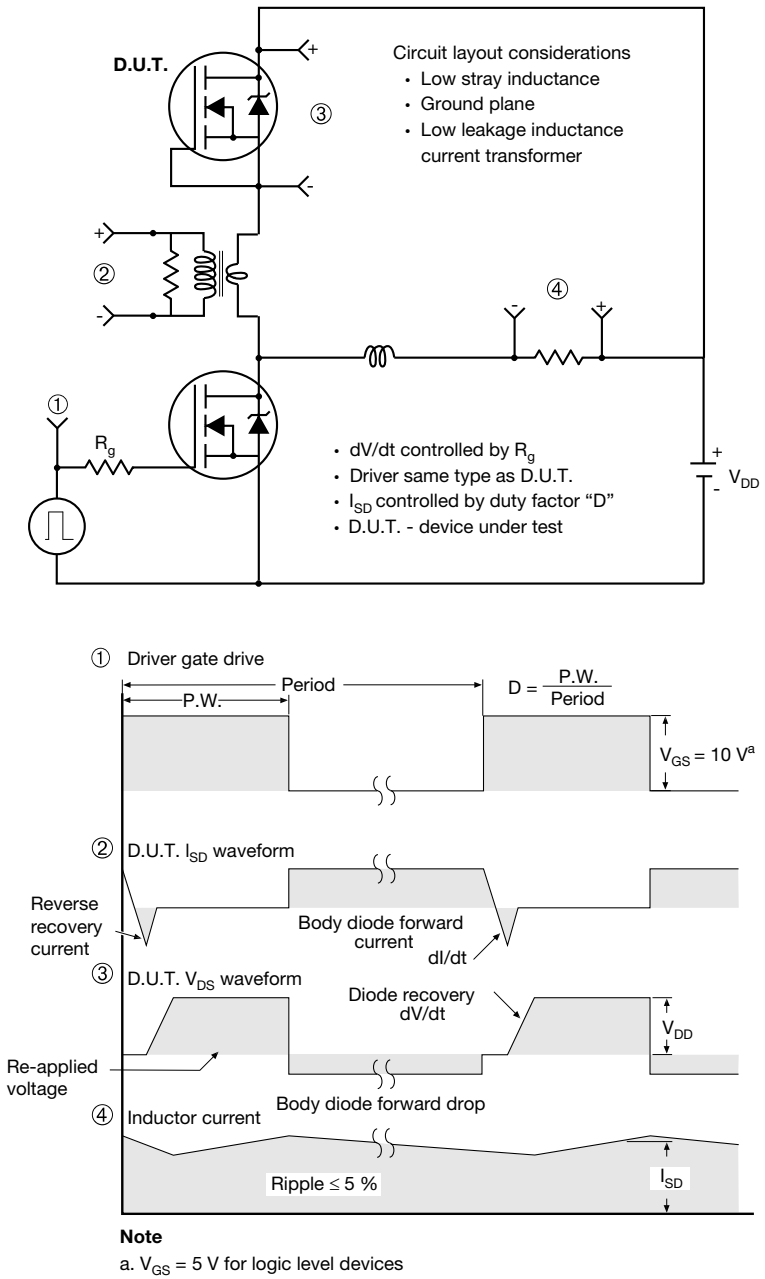


Fig. 13b - Gate Charge Test Circuit

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Peak Diode Recovery dV/dt Test Circuit



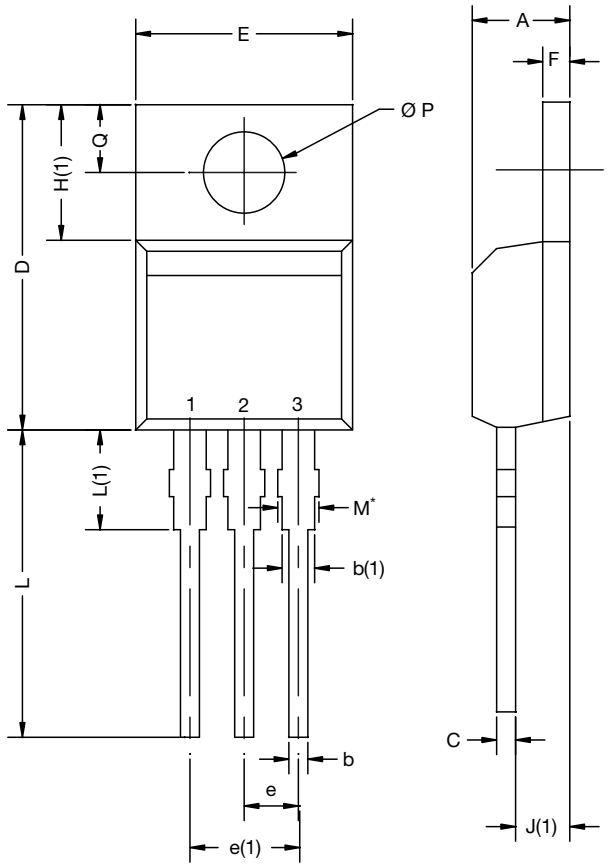
Note

a. V_{GS} = 5 V for logic level devices

Fig. 11 - For N-Channel

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TO-220-1



DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.24	4.65	0.167	0.183
b	0.69	1.02	0.027	0.040
b(1)	1.14	1.78	0.045	0.070
c	0.36	0.61	0.014	0.024
D	14.33	15.85	0.564	0.624
E	9.96	10.52	0.392	0.414
e	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.10	6.71	0.240	0.264
J(1)	2.41	2.92	0.095	0.115
L	13.36	14.40	0.526	0.567
L(1)	3.33	4.04	0.131	0.159
Ø P	3.53	3.94	0.139	0.155
Q	2.54	3.00	0.100	0.118
ECN: E21-0621-Rev. D, 04-Nov-2021 DWG: 6031				

Note

- M* = 0.052 inches to 0.064 inches (dimension including protrusion), heatsink hole for HVM

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